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**Brief Reports**

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*Brief Reports are short papers which report on completed research or are addenda to papers previously published in the Physical Review. A Brief Report may be no longer than 3½ printed pages and must be accompanied by an abstract and a keyword abstract.*

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**Configuration of states in  $^{210}\text{Bi}$  from  $^{209}\text{Bi}(\vec{d}, p)$** 

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The reaction  $^{209}\text{Bi}(\vec{d}, p)$  has been used to study the structure of the ground state multiplet of  $^{210}\text{Bi}$ . The cross section and vector analyzing power were measured at  $E_d = 12$  MeV for angles between  $65^\circ$  and  $100^\circ$ . No evidence of configuration mixing was seen in the analyzing power measurements. The cross section measurements confirm previous observations of fragmentation of the  $8^-$  level at 580 keV.

[NUCLEAR REACTIONS  $^{209}\text{Bi}(\vec{d}, p)$ ,  $E_d = 12.0$  MeV; measured  $\sigma(\theta)$ ,  $i T_{11}(\theta)$  for  $65^\circ < \theta < 100^\circ$ ; natural target.]

The ground state multiplet of  $^{210}\text{Bi}$  consists of \_\_\_\_\_ studied the vector analyzing power for transitions \_\_\_\_\_



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configuration, it has been suggested<sup>3</sup> that the admixture to the 580 keV level is primarily

$$\pi f_{7/2} \nu g_{9/2}.$$

The vector analyzing power measurements for the levels in the ground state multiplet of  $^{210}\text{Bi}$  and for the  $8^-$  level at 916 keV are shown in Fig. 2. The solid line is a smooth curve drawn through the measured analyzing power points for the entire ground state multiplet, and thus represents the average analyzing power.

The analyzing power measurements display a gradual trend toward more negative values of  $iT_{11}$  with increasing excitation energy. Distorted-wave calculations suggest that this effect may be the result of a  $Q$ -value dependence of the vector analyzing power. This point is illustrated in Fig. 3. The solid and dashed curves in Fig. 3 show distorted-wave Born approximation (DWBA) calculations for pure  $g_{9/2}$  transitions with  $Q$  values of 2.11 and 1.80 MeV, corresponding to the  $0^-$

of  $iT_{11}$  as a function of excitation energy for each level in the ground state multiplet and for the  $8^-$  level at 916 keV. The solid curve is a linear fit to the data points shown. The smooth dependence of the average analyzing power on the excitation energy supports the idea that the differences in  $iT_{11}$  between the various transitions result from  $Q$  dependence of the vector analyzing power rather than from configuration mixing.

The cross section and vector analyzing power measurements of the present experiment suggest that the  $^{209}\text{Bi}(d, p)$  transitions to low-lying states in  $^{210}\text{Bi}$  are pure  $j^\pi = \frac{9}{2}^+$ . Thus, the  $iT_{11}$  data are consistent with the suggestion that the admixture in the 580 keV level is  $\pi f_{7/2} \nu g_{9/2}$ . However, because of the preference of low energy ( $d, p$ ) reactions for low angular momentum transfers, the present data cannot rule out the possibility of a significant admixture of  $\pi h_{9/2} \nu i_{11/2}$  in the level. The cross section measurements confirm earlier